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## STRAIN MAPPING BY HIGH ANGULAR RESOLUTION EBSD (AKA HR-EBSD)

Acknowledgments: Angus Wilkinson, Angus Kirkland, Fionn Dunne, Jun Jiang, Vivian Tong, David Wallis, Lars Hansen, Aimo Winkelmann

### Outline

- EBSD vs HR-EBSD
- Examples
- Strain and deformation
- HR-EBSD fundamentals
- Accuracy, precision and sensitivity
- Pattern Remapping
- Summary

### EBSD vs HR-EBSD

3

	EBSD	HR-EBSD
Absolute Orientation	~2°	No
Misorientation	~0.1 to 0.5°	~0.006°
Deformation –		
GNDs @ 1µm step	> 3x10 <sup>13</sup>	> 3x10 <sup>11</sup>
GNDs @ 100nm step in lines / m <sup>2</sup> (b = 0.3nm)	> 3x10 <sup>12</sup>	> 3x10 <sup>10</sup>
Relative elastic strain	No	Deviatoric strain ± 1x10 <sup>-4</sup>
Relative residual stress (Type III – within grain)	No	Anisotropic Hooke's law ± 20 MPa (E=200GPa)
Example tasks:	Microstructure, Texture, Grain size, etc.	<b>Deformation</b> i.e. elastic strain, misorientation & residual dislocation content

#### **Strain and deformation**

#### Strain and deformation

- Two types of strain tensor
  - Elastic (i.e. stress)
  - Plastic

# ● Elastic leads to a change in bond length / angle → HR-EBSD!

• Plastic more tricky…

#### Strain and deformation

Plastic shape change due to slip etc. Lattice remains un-deformed

 $F = F^e F^p$ 

Elastic shape change
→ Bond stretch etc.
→ Lattice orientation due to slip etc.

$$\mathbf{F} = \begin{pmatrix} F_{11} & F_{12} & F_{13} \\ F_{21} & F_{22} & F_{23} \\ F_{31} & F_{32} & F_{33} \end{pmatrix} = \begin{pmatrix} \frac{dx}{dX} & \frac{dx}{dY} & \frac{dx}{dZ} \\ \frac{dy}{dX} & \frac{dy}{dY} & \frac{dy}{dZ} \\ \frac{dz}{dZ} & \frac{dz}{dZ} & \frac{dz}{dZ} \end{pmatrix} + \mathbf{I}$$

(dr dr dr)

Strain is fundamentally a 2<sup>nd</sup> rank tensor

Many metrics are proxies  $\rightarrow$  use with care!

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#### Potato deformation

(from http://www.continuummechanics.org/cm/deformationgradient.html)

#### HR-EBSD and F<sup>e</sup>

 Follow change in interplanar angles within the diffraction (with high precision)

Apply simple geometry and extract F<sup>e</sup>

 Split F<sup>e</sup> into elastic strain (deviatoric) & lattice rotation

 Use lattice rotation gradients to evaluate GNDs (a symptom of plastic strain)



Hydrostatic Strain  $\rightarrow$  No



Deviatoric Strain  $\rightarrow$  Yes



#### Strain & rotation



#### Comparison with models

• 50g force

Concrete damage model + cohesive zones along <110>



Britton, Jiang, Clough, Tarleton, Kirkland, and Wilkinson (2013) Ultramicroscopy – Part 2

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#### **Comparing Strain Fields**



11

#### Jiang, Britton and Wilkinson (2015) IJP

#### Microstructure – dislocation structure correlations (Cu)

#### Evolution of dislocation structure with uniaxial strain

- Avoids thin films
- Cover large areas
- Access many grains
- Correlate with tensor quantities
  - Schmid factor, Taylor factor etc.
- Can also compare with crystal plasticity models



Jiang, J., Britton, T.B., and Wilkinson, A.J. (2013) Acta Mat.

#### Big data...



 $\sim$ 500µm square = 1500 grains

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 $\sim$ 110µm square = 30-60 grains

Britton, Jiang, Karamched and Wilkinson (2013) JOM

#### Multi-modal

13



Britton and Wilkinson (2013) *Acta Mat* Guo, Y., Britton, T.B. and Wilkinson, A.J. (2014) *Acta Mat* 

### New insight – g.b. strength

Guo, Y., Collins, D.M., Tarleton, E., Hoffman, F., Tischler, J., Liu, W., Xu, R., Wilkinson, A.J. and Britton, T.B. (2015) *Acta Mat* 



Macroscopic Tensile Stress



#### Verifying Eshelby, Frank and Nabarro



Measurement of stress and strain near g.b.

fitting:  $\sigma_{31} = A + K / \sqrt{D}$ K = 0.42 MPa $\sqrt{m}$ 



Normalised shear stress vs normalised distance from a screw dislocation pile up Redrawn from Eshelby, Frank, Nabarro (1951)

#### **HR-EBSD** Rocks

All we need are good EBSD patterns...

 Other material systems can be explored
 e.g. Metals, Semiconductors, Rocks, Intermetallics etc.

 Example here – dislocations in olivine
 Good correlation between dislocation decoration (oxidation) & GND measurements
 Important for understanding earth formation Dislocations decorated by oxidation



GND density from HR-EBSD Step size: 0.25 µm







### **HR-EBSD Fundamentals**

#### Accessing Elastic Strain – HR-EBSD

#### EBSD pattern = direct projection of lattice planes



#### Accessing Elastic Strain – HR-EBSD

 EBSD pattern = direct projection of lattice planes

 Strain of crystal = movement of bands



#### Measuring shifts with image correlation

- 20+ ROI used (offline)
   Select ROIs → FFT
  - Apply filter
- Compare unstrained (1) vs strained (2) pattern
  - Upsample peak in XCF of ROI
    xshift= -6.06 (pixels)
    yshift= -4.59
- 'Just' an educated 'guess' of the translation vector between test & reference



Method described in Britton, Jiang, Karamched and Wilkinson in JOM (2013)

#### HR-EBSD – shifts to strains



$$r_{x}(A_{xx}-A_{zz}) + r_{y}A_{xy} + r_{z}A_{xz} + \frac{r_{x}r_{x}}{r_{z}}A_{zx} + \frac{r_{y}r_{x}}{r_{z}}A_{zy} = Q_{x}$$
  
$$r_{x}A_{yx} + r_{y}(A_{yy}-A_{zz}) + r_{z}A_{yz} + \frac{r_{x}r_{y}}{r_{z}}A_{zx} + \frac{r_{y}r_{y}}{r_{z}}A_{zy} = Q_{y}$$



#### Error Metrics\* - measure precision

#### Mean Angular Error (MAE)

- Solve an over determined problem (shifts  $\rightarrow$  deformation)
  - Only 4x regions of interest (ROI) needed
  - Typically use 20+ ROI
- Tests how well shifts + remapping 'fit' a deformation gradient
- Need a value < strains of interest</li>
- Low values can hide systematic errors
- Measure correlation peak height (PH)
  - Normalise with 1 (autocorrelation) and 0 = no correlation
  - Calculate geometric mean → 1 bad ROI reduces PH strongly
  - Typically values >0.3 are 'ok' (higher is better!)

EBSD Local Misorientation Map with Crystal Orientation Overlay



Scale bar =  $5\mu m$  and step size =  $1\mu m$ 

PH







#### **Reference selection**

- HR-EBSD measures difference in strain + orientation between test & reference pattern
- Reference within same grain
   & same sample
   & microscope cannot be disturbed
  - 1 $\mu$ m of misalignment = 1/20<sup>th</sup> pixel = 1x10<sup>-4</sup> in strain error
- Simulations as reference patterns requires

great patterns  $\rightarrow$  dynamical patterns likely ok (e.g. EM Soft + Dynamics) & great knowledge of pattern centre  $\rightarrow$  still not good enough & great knowledge of camera optics  $\rightarrow$  not well tackled (yet?)

\*see Britton et al. (2010) Ultramicroscopy for challenges to be overcome

#### **Reference selection**

- Choose something clear (single pattern, crisp)
- Precise location does not matter
- Relative strain + rotation measured
   Can 're-zero' as needed
- Reference selection for GND measurements not important
  - Local curvature

#### Illustration of the effect of reference pattern selection From Mikami et al. (2015) *Mat Sci Eng A*



#### Data presented in Britton and Wilkinson (2012) Materials Today

#### Example – Si indentation



#### Closure, Nye Tensor and GNDs

In a deformed crystal (w/o cracks) the displacement field is continuous

• Therefore:  $curl(F^e) = -curl(F^p)$ 

• Evaluate curl(F<sup>e</sup>) to understand some plastic strain gradients

• Field of GND analysis – using the Nye tensor [1]

### Measuring dislocation content (GNDs)

- Map lattice rotations
- Calculate curvature •  $K_n = d\omega_{ij}/dx_k$
- Nye's dislocation tensor [1] relates curvature to dislocation content





Etch pits revealing a low angle grain boundary containing an array of geometrically necessary dislocations (GNDs) [From Hull and Bacon, Introduction to Dislocations]

#### **Curvatures & Densities**

- FCC = 18 dislocation types
  - 6 screw, 12 edge
- (often\*) overdetermined problem
- Solve with physically motivated minimisation:
  - use linprog & weight according to line energies

$$\begin{pmatrix} b_{1}l_{1} - \frac{1}{2}b.l \rightarrow S^{\text{th}} \\ b_{1}l_{2} \\ b_{1}l_{3} \\ b_{2}l_{1} \\ b_{2}l_{2} - \frac{1}{2}b.l \\ b_{2}l_{3} \end{pmatrix} \begin{pmatrix} \rho \\ \vdots \\ S^{\text{th}} \end{pmatrix} = \begin{cases} \frac{\partial \omega_{23}}{\partial x} \\ \frac{\partial \omega_{31}}{\partial x} \\ \frac{\partial \omega_{12}}{\partial x} \\ \frac{\partial \omega_{23}}{\partial x} \\$$

1dwaa

$$A\begin{pmatrix}\rho\\.\\\boldsymbol{S^{\mathrm{th}}}\end{pmatrix} = K$$

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Except in low symmetry materials, like rocks – see Wallis et al. (2016) Ultramicroscopy

Jiang, Britton and Wilkinson (2010) Phil Mag

#### Example map

- O Cu − 2% plastic strain
- Reveals cell structure
- Relationship of GND distributions with microstructure...



### Accuracy, Precision & Sensitivity

#### Accuracy, Precision and Sensitivity

 Fundamentally image correlation used to compare diffraction patterns and extract 'high quality' data

Precision

- ability to recover same result many times

Accuracy

- ability to recover correct answer

Sensitivity

- what sort of changes can we observe





#### Measuring Precision – Dynamical Simulations

- Generate a high quality 4MG simulation
  - ecpdist courtesy of Dr Aimo Winklemann
- Beam shift virtually
- Bin the image
- Measure (normalised) precision for each binning level



ege

#### **Capturing Diffraction Patterns**

#### • Variables:

- Hardware (~fixed)
- Exposure time/probe current
  - i.e. electron budget
- Camera binning



#### One Pattern → Five Patterns



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### Precision vs budget and binning

- Measure variation EBSP movement due to beam shift
  - 10 pairs of patterns
  - Different binning (hardware & software)
  - Different exposure times
- Measure precision
  - Averaging standard deviation of 50 ROIs for the difference



### Implications

- Sensitivity proportional to precision
- 0.1 normalised pixels in 1000 pixels
   ~ 1x10<sup>-4</sup> in sensitivity\*
- 2x2 binning, faster exposures or 'fast cameras' ok!
  - Hough resolution:
     0.5° = 8 pixels shift
  - Just 0.5 pixels shift sensitivity?
     0.02° misorientation resolution!



# HR-EBSD resolution & precision

(Effective) spatial resolution – ~typical EBSD

- c. 20 x 60 x 20 nm<sup>3</sup>  $\rightarrow$  see figure to right [1]
- Typical precision [2,3]
  - ~1x10<sup>-4</sup> in strain
  - ~1x10<sup>-4</sup> / 0.006° in rotation
    - vs Hough at 0.8x10<sup>-2</sup> / 0.5°
    - Up to ~1x10<sup>-5</sup> reported with great patterns

#### Could be better with better hardware... [4]

 Tong, Jiang, Wilkinson and Britton (2015) Ultramicroscopy
 Wilkinson, Meaden and Dingley (2006) Ultramicroscopy
 Britton, Jiang, Karamched, Wilkinson (2013) JOM
 Britton et al. (2013) "Assessing the precision of strain measurements using electron backscatter diffraction" – Parts 1 and 2" in *Ultramicroscopy*



# **HR-EBSD: Remapping**

#### Pattern remapping

Output Strain → ~10s of pixels shifts
Output Strain → ~1s pixel shifts

- Estimate finite rotation matrix, R<sup>f</sup>, from measured (infinitesimal) rotations
- Interpolate test pattern into reference orientation
  - Bicubic in matlab (gridfit)

 $\mathbf{R}^{f} = \begin{pmatrix} \cos \omega_{12} & \sin \omega_{12} & 0 \\ -\sin \omega_{12} & \cos \omega_{12} & 0 \\ 0 & 0 & 1 \end{pmatrix} \times \\ \begin{pmatrix} 1 & 0 & 0 \\ 0 & \cos \omega_{23} & \sin \omega_{23} \\ 0 & -\sin \omega_{23} & \cos \omega_{23} \end{pmatrix} \times \\ \begin{pmatrix} \cos \omega_{31} & 0 & -\sin \omega_{31} \\ 0 & 1 & 0 \\ \sin \omega_{31} & 0 & \cos \omega_{31} \end{pmatrix}$ 

 $r' = R^f r$ 

 $= \mathbf{R}^{f}$ 

**Remapped Test** 

Test

### Remapping

- 1<sup>st</sup> pass measurement of rotation
- Use to remap intensities
  - Need projection info
  - Improve XCF
- Cross correlation for strains + precise rotations
- Recombine the maths in finite deformation framework



#### Measuring strains with large rotations

- Comparing simulated patterns (tetragonal distortion)
- Errors introduced when rotations large
- Due to non-translational distortions
- Use pattern remapping to fix
- Needs a good pattern centre measurement!



Wilkinson, A.J., Tarleton, E. Vilalta-Clemente, A., Jiang, J., Britton, T.B. and Collins, D.M. (2014) PRL

#### More reasonable stresses?



# **HR-EBSD: Summary**

### Summary

- Compare 2+ good patterns ... many many times (an embarrassing problem)
- Software evaluates F<sup>e</sup>
- Explore residual elastic strain tensor (i.e. stress) within grains
- - Only a symptom of part of plastic strain...
- Use of simulations, at present, is a limited to algorithm development\*

<sup>44</sup> \*see Britton et al. (2010) Ultramicroscopy for challenges to be overcome